

Ultra Low Dropout Positive Fixed Linear Regulator

IRUH50P253A1M +5.0Vin to +2.5Vout at 3.0A

Product Summary

www.DataShee

Part Number	Dropout	lo	V _{in}	V _{out}	
IRUH50P253A1M	0.4V	3.0A	5.0V	2.5V	

The IRUH50P253A1M is a space qualified, ultra low

dropout linear regulator designed specifically for space

applications. This product has been characterized to a total

ionizing dose of 1.0 Mrad(Si) per MIL-STD-883, Method

1019 at both high and low dose rates under biased and

unbiased conditions to account for ELDRS effects in bipolar devices. The ultra low dropout voltage of 0.4V@ 3A makes

the part particularly useful for applications requiring low



Features:

- Total dose to 1.0 Mrad(Si) and low dose capability to 500 Krad(Si) allows use in space applications
- Single Event latchup Immune LET = 84 MeV/(mg/cm²) Fluency = 1 x 10⁹ lons/cm²
- Low noise, higher efficiency
- Ultra low dropout voltage of 0.4V@ 3A out significantly reduces power consumption
- Remote shutdown permits power sequencing to be easily implemented
- Hermetic 8-Lead Flat Pack ensures higher reliability
- Space Level Screened
- This part is also available in MO-078AA Package as IRUH50P253B1M

Absolute Maximum Ratings

noise and higher efficiency.

Absolute maximum ratings						
Parameter	Symbol	Value	Units			
Output Current	Io	3.5	Α			
Input Voltage	V _{IN}	7.0	V			
Power Dissipation, T _C = 25°C	P _{TOT}	19	W			
Thermal Resistance, Junction to Case	R _{THJC}	6.5	°C/W			
Operating Temperature Range	T _J	-55 to +125				
Storage Temperature Range	T _S	-65 to +150	°C			
Lead Temperature	T _L	300				

www.irf.com 1 11/15/05

Pre-Radiation

Electrical Characteristics @T_C = 25°C (Unless Otherwise Specified)

	Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
		$V_{IN} = 5.0V, I_O = 1.5A$		2.475	2.5	2.525	V
	Output Voltage	$V_{IN} = 4.5V, I_O = 50mA$		2.375		2.625	
www.DataShee		$V_{IN} = 4.5V, I_O = 3.0A$	V _{OUT}	2.375	-	2.625	
		$V_{IN} = 5.5V, I_O = 50mA$		2.375	-	2.625	
		$V_{IN} = 5.5V, I_O = 3.0A$		2.375	-	2.625	
	Input Voltage Range - Operating	$I_{O} = 3.0A$	V_{IN}	4.5	1	6.5	
	Dropout Voltage	$I_O = 3.0A, V_{OUT} = 2.5V$	V_{DROP}	-	-	0.4	
	Current Limit	V _{IN} = 5.0V, Overcurrent Latchup	I _{LATCH}	3.0	-	-	Α
	Ripple Rejection	$F = 120Hz, I_O = 50mA$		65	-	-	dB
	Shutdown Source Current	V _{SHDN} = 5.0V	I _{SHDN}	1	200	-	μΑ
	Shutdown Pin Threshold ①	$V_{IN} = 5.0V$	V _{SHDN}	1.0	-	1.6	
	Output Voltage at Shutdown	$V_{IN} = 5.0V$, $I_{O} = 50$ mA, $V_{SHDN} = +5.0V$	V _{OUT} (SHDN)	-0.1	-	+0.1	V

Pre-Radiation

Electrical Characteristics $@T_C = -55^{\circ}C$ to 125°C (Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{IN} = 5.0V, I_O = 1.5A$		2.375	2.5	2.625	V
	$V_{IN} = 4.5V, I_O = 50mA$		2.375	-	2.625	
Output Voltage	$V_{IN} = 4.5V, I_O = 3.0A$	V _{OUT}	2.375	-	2.625	
	$V_{IN} = 5.5V, I_O = 50mA$		2.375	-	2.625	
	$V_{IN} = 5.5V, I_O = 3.0A$		2.375	-	2.625	
Input Voltage Range - Operating I _O = 3.0A		V_{IN}	4.5	1	6.5	
Dropout Voltage	age $I_{O} = 3.0A, V_{OUT} = 2.5V$		1	1	0.4	
Current Limit	V _{IN} = 5.0V, Overcurrent Latchup	I _{LATCH}	3.0	1	-	Α
Ripple Rejection	ejection $F = 120Hz, I_O = 50mA$		65	1	-	dB
Shutdown Source Current V _{SHDN} = 5.0V		I _{SHDN}	1	200	-	μΑ
thutdown Pin Threshold ① $V_{IN} = 5.0V$		V _{SHDN}	1.0		1.6	
Output Voltage at Shutdown	$V_{IN} = 5.0V$, $I_O = 50$ mA, $V_{SHDN} = +5.0V$	V _{OUT (SHDN)}	-0.1		+0.1	V

For notes, please refer to page 3



Post-Radiation

Electrical Characteristics $@T_C = 25^{\circ}C$ (Unless Otherwise Specified)

	Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
		$V_{IN} = 5.0V, I_{O} = 1.5A$		2.375	-	2.625	
www.DataSheef	Qutput Voltage	$V_{IN} = 4.5V, I_{O} = 50mA$	V _{OUT}	2.375	-	2.625	V
		$V_{IN} = 4.5V, I_{O} = 3.0A$		2.375	-	2.625	
		$V_{IN} = 5.5V, I_{O} = 50mA$		2.375	-	2.625	
		$V_{IN} = 5.5V, I_O = 3.0A$		2.375	-	2.625	
	Current Limit	V _{IN} = 5.0V	I _{MAX}	3.0	-	-	Α
	Ripple Rejection	F = 120Hz, I _O = 50mA		40	-	-	dB
	Output Voltage at Shutdown	$V_{IN} = 5.0V$, $I_O = 50$ mA, $V_{SHDN} = +5.0V$	V _{OUT} (SHDN)	-0.1	-	+0.1	٧

Notes for Electrical Characteristic Tables

 $[\]odot$ V_{Shutdown} ramp from 0.8V to 4.8V, output monitored for a 100mV drop below the nominal specification for V_{out}

Pre-Radiation Characteristics

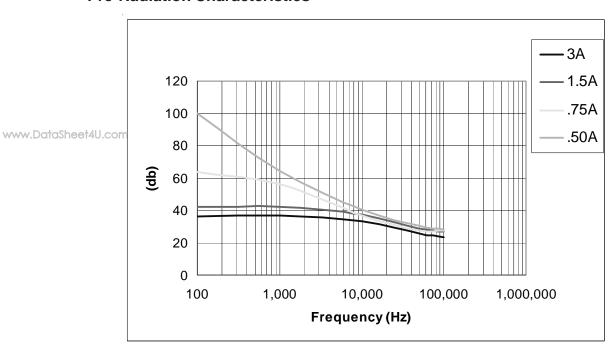


Fig 1. Ripple Rejection Vs Frequency

Radiation Performance Characteristics

Test Conditions		Min	Тур	Unit	
	MIL-STD-883, Method 1019				
Total Ionizing Dose (Gamma)	Operating Bias applied during exposure	1,000		Krads (Si)	
	Full Rated Load, Vin=5.0V				
Neutron Fluence	MIL-STD-883, Method 1017	1.00E+09	1.00E+13	Neutrons/cm ²	
Single Event effects SEU, SEL, SEGR, SEB	, ,			MeV*cm²/mg	
, ,	Full Rated Load, Vin=5.0V				

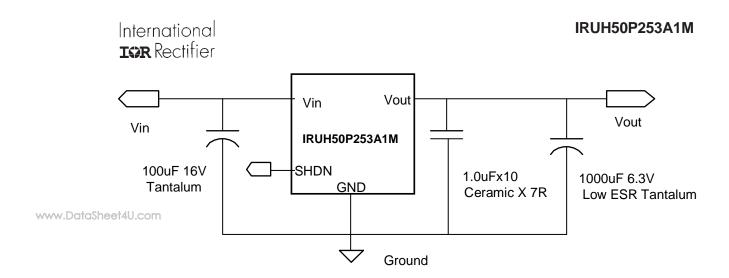


Fig 2. Typical Application Circuit

Input Capacitance

Recommended input capacitance for a generic application is a $100\mu F$, 16V tantalum capacitor. However, the input capacitance is not critical to the stability of the regulator and is therefore application dependant. In designs with a clean bus voltage that is situated close to the input of the regulator, only a small ceramic capacitor will be needed to decouple high frequency noise. On the other hand, in designs with a noisy bus, a larger capacitor will be needed. Care should be taken to ensure that the input to the regulator is sufficiently free of noise and disturbances.

Output Capacitance

Like most ultra low dropout voltage regulators, IRUH50P253A1M requires the use of output capacitors as part of the device frequency compensation. The device requires a minimum of $220\mu F$ tantalum to ensure stability.

Many different types of capacitor are available and have widely varying characteristics. These capacitors differ in capacitor tolerance, equivalent series resistance (ESR), equivalent series inductance and capacitance temperature coefficient. The IRUH50P253A1M frequency compensation optimizes frequency response with low ESR capacitors. In general, use capacitors with an ESR of less than $50m\Omega$ for heavy load applications.

High quality bypass capacitors must be also be used to limit the high frequency noise generated by the load. Multiple small ceramic capacitors are typically required to limit parasitic inductance (ESL) and ESR in the capacitors to acceptable levels.

The upper limit of the capacitance is governed by the delayed over-current latch function of the regulator. The regulator has a protection circuit that will latch the device off in the event of a short circuit. However, since it is known that the regulator will draw a large in-rush current upon startup, the latch-off is delayed by about 10ms to allow the outout capacitors to charge to a steady state without shutting down. During this period, the regulator will have an output current at its maximum of around 5A typical. Therefore, the maximum output capacitance can be as high as $20,000\mu F$ without causing device to latch-off during start-up.

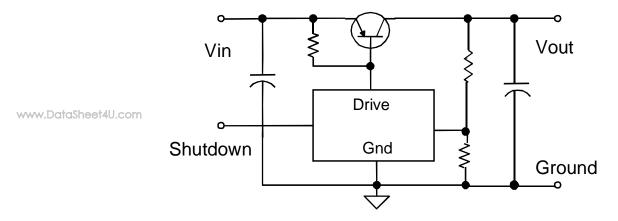


Fig 3. Simplified Schematic Circuit

Space Level Screening Requirements

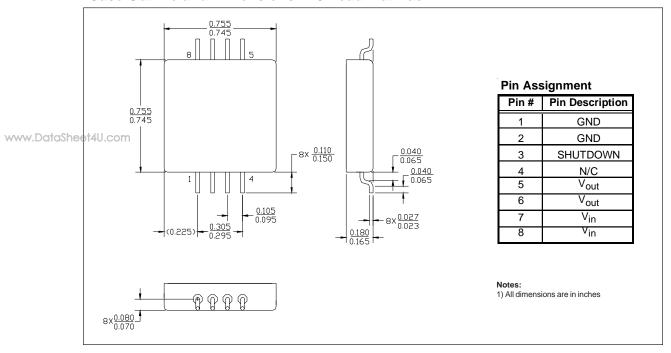
TEST/INSPECTION	SCREENING LEVEL	MIL-STD-883
	SPACE	METHOD
Pre Seal Burn-In	Optional	1030
Nondestructive Bond Pull	100%	2023
Internal Visual	100%	2017
Temperature Cycle	100%	1010
Constant Acceleration	100%	2001
Mechanical Shock	100%	2002
PIND	100%	2020
Pre Burn-In-Electrical	100%	
Burn-In	100%	1015
Final Electrical	100%	
Seal	100%	1014
Radiographic	100%	2012
External Visual	100%	2009

Note:

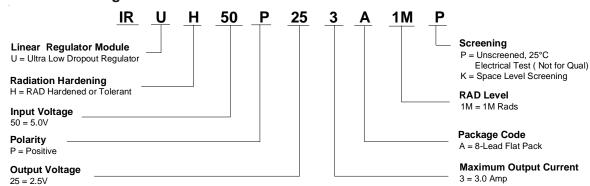
International Rectifier doesnot currently have a DSCC certified Radiation Hardness Assurance Program

International TOR Rectifier

Case Outline and Dimensions - 8-Lead Flat Pack



Part Numbering Nomenclature



International TOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 IR LEOMINSTER: 205 Crawford St., Leominster, Massachusetts 01453, USA Tel: (978) 534-5776

TAC Fax: (310) 252-7903

Visit us at www.irf.com for sales contact information. Data and specifications subject to change without notice. 11/2005